

PdAu Based Resistive Hydrogen Sensor in Anaerobic Environment

Clément Occelli, Ph.D. Student
Tomas Fiorido, Carine Perrin-Pellegrino, Jean-Luc Seguin

clement.occelli@im2np.fr
jean-luc.seguin@im2np.fr

Aix-Marseille Univ, Univ Toulon, CNRS, IM2NP
Marseille, France .

Clément Occelli received his engineering degree in Materials from the Polytech'Marseille engineering school, Marseille, in 2016. During this period, he was at the IM2NP institute at the Aix-Marseille University in France for 3 months, working on WO_3 sensor for ozone detection. He was in industry from 2017 until 2019 where his work was focused on materials and products testing. He is currently a 2nd year Ph.D. student back to the IM2NP Institute, developing hydrogen sensors for anaerobic environment.



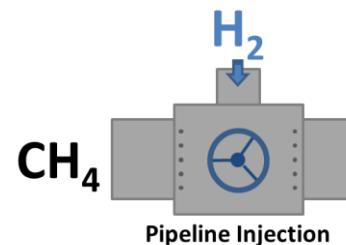
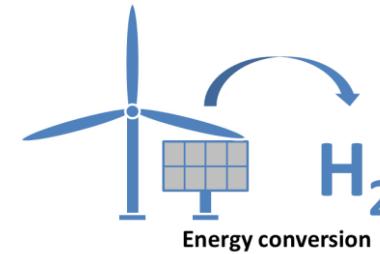
- I. Context, technology and detection principle**
 - a) Environmental context
 - b) Palladium gold alloy for hydrogen detection
 - c) Introduction to resistive sensor
 - d) Detection and characterization principle
- II. Thin film deposition and crystalline structure**
 - a) PdAu thin film deposition
 - b) Effect of annealing on film microstructure
- III. Sensor electrical characterization**
 - a) Sensor test bench
 - b) Sensor performance at different temperatures
 - c) Best operative temperature
 - d) Sensor testing at various hydrogen concentrations
- IV. Conclusion and perspective**

I. Context, technology and detection principle

Current climate change drives for greenhouse gas emission reduction

Hydrogen is a promising energy carrier :

- ✓ Low environmental footprint
- ✓ Complementary use with renewable energy
- ✓ Use of current gas pipeline



Injection of Hydrogen in pipeline must not exceed 20%

Various hydrogen sensors exist for leak detection in air only few have been reported operating in anaerobic environment



Pd is a promising candidate for H₂ detection but cannot be used alone

Advantage

- ✓ Selectivity to hydrogen
- ✓ Operate without oxygen and low T°
- ✓ Sensitivity to ppm

Drawback

- ✗ Measurement hysteresis
- ✗ Ageing of material in H₂
- ✗ Slow detection (min)

Solution by addition of another element → Fabrication of an alloy

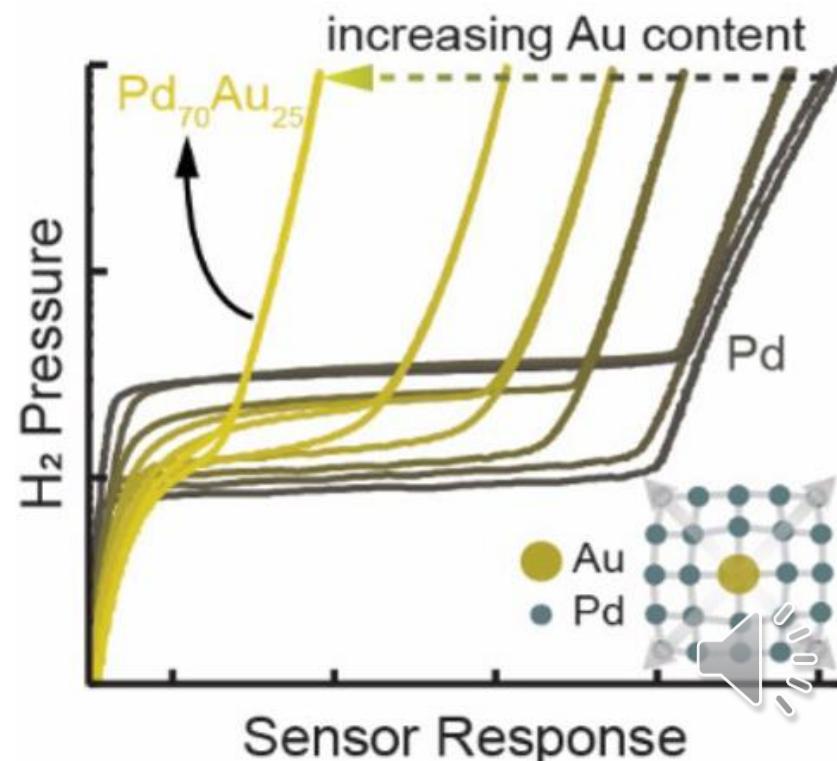
Addition of Gold :

- Suppression of hysteresis
- Protect layer from delamination
- Fasten detection

But

- Lower sensitivity

Best compromise about 20-25% in literature



Resistive sensor structure

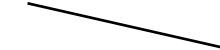
- 1) Sensitive film / Measuring electrode

Gas interaction
/ Information reading



- 2) Substrate (Si/SiO₂)

Electrical insulation

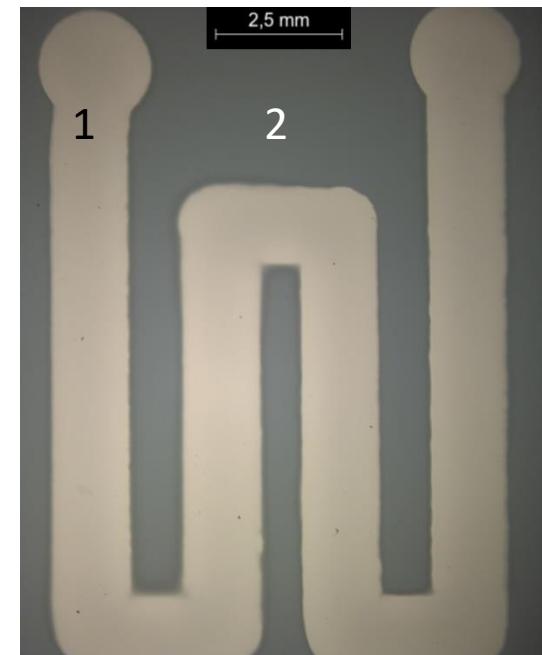


- 3) Heating device

Reaction control



Sensor Design



1 . PdAu sensitive layer
2 . Si/SiO₂ substrate

Detection principle :

Pd and PdAu crystallize in a FCC structure

Absorbed hydrogen occupy octaedral interstitial site

Hydrogen site occupation induces electron scattering which increases material resistivity

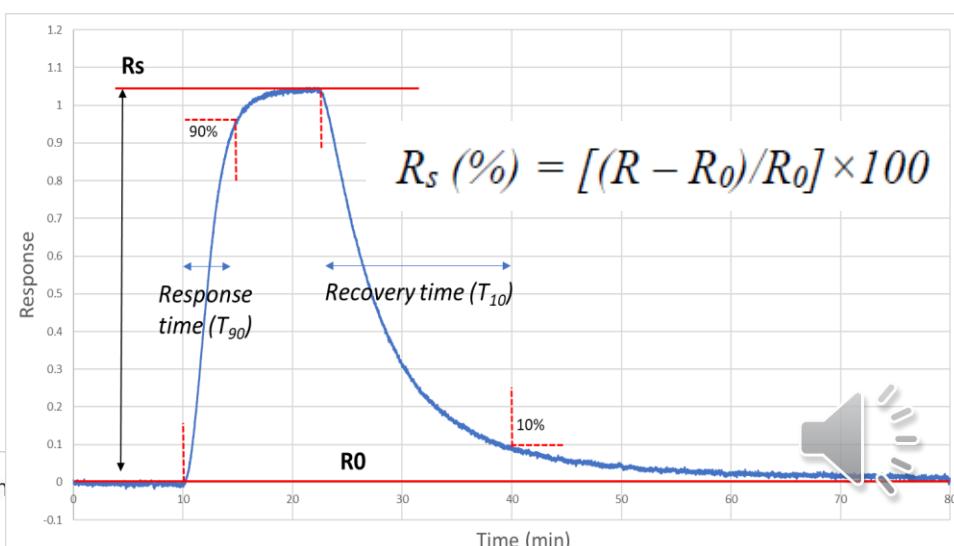
→ Sensing principle

Tools for performance characterization:

Sensor response (Rs) : Comparaison of resistance under gas (R) to reference value (R₀)

Response time (T₉₀) : Time to reach 90% of Rs value

Recovery time (T₁₀) : Time to return to 10% of Rs



II. Thin film deposition and crystalline structure



■ Film Deposition

RF magnetron sputtering

Ti adhesion layer

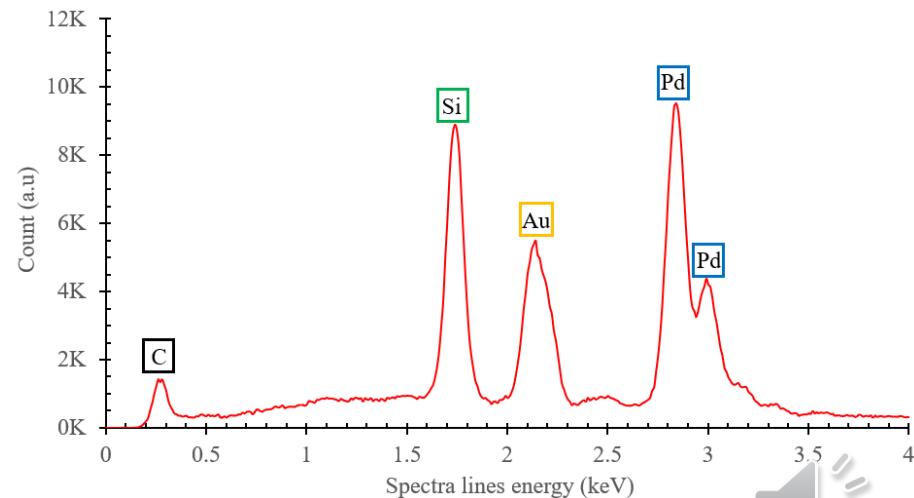
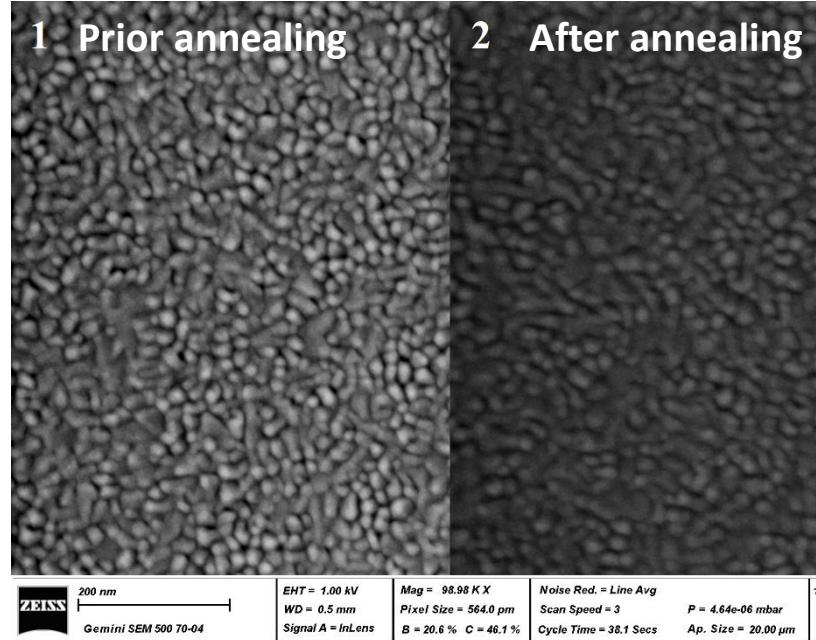
PdAu Layer thickness : 120nm

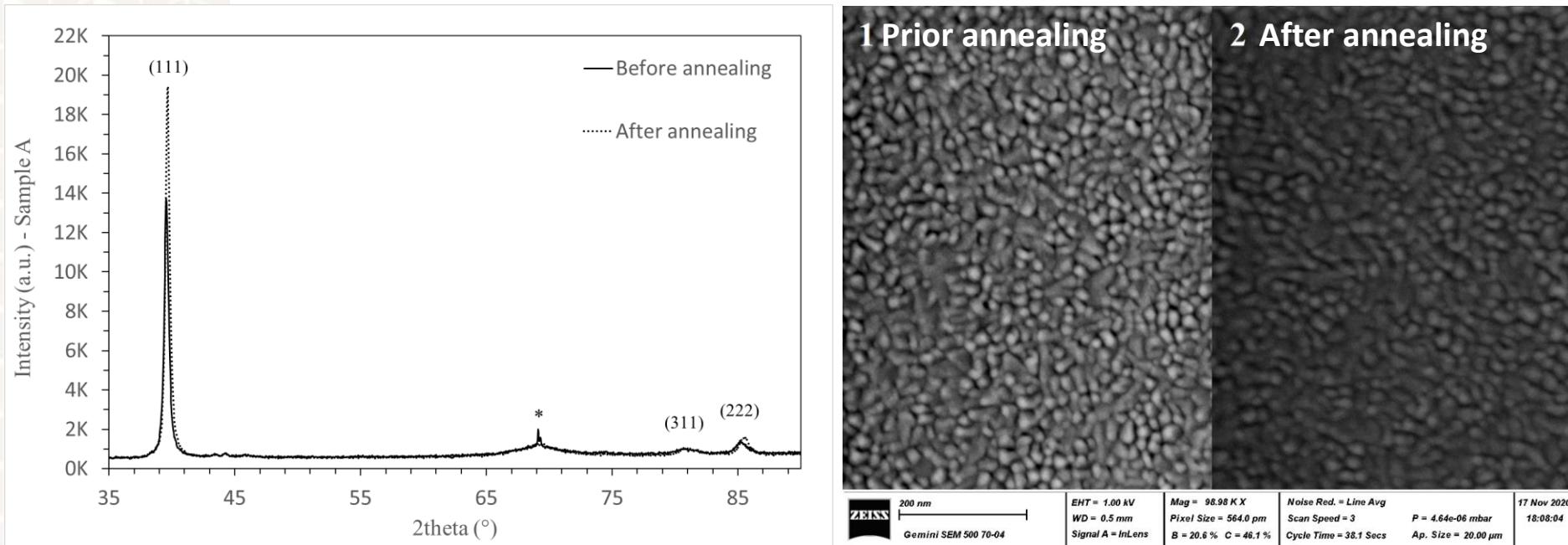
■ Annealing

200°C in N₂ for several hours

■ EDXS measurements (after annealing)

Estimated composition of 80%Pd and 20%Au



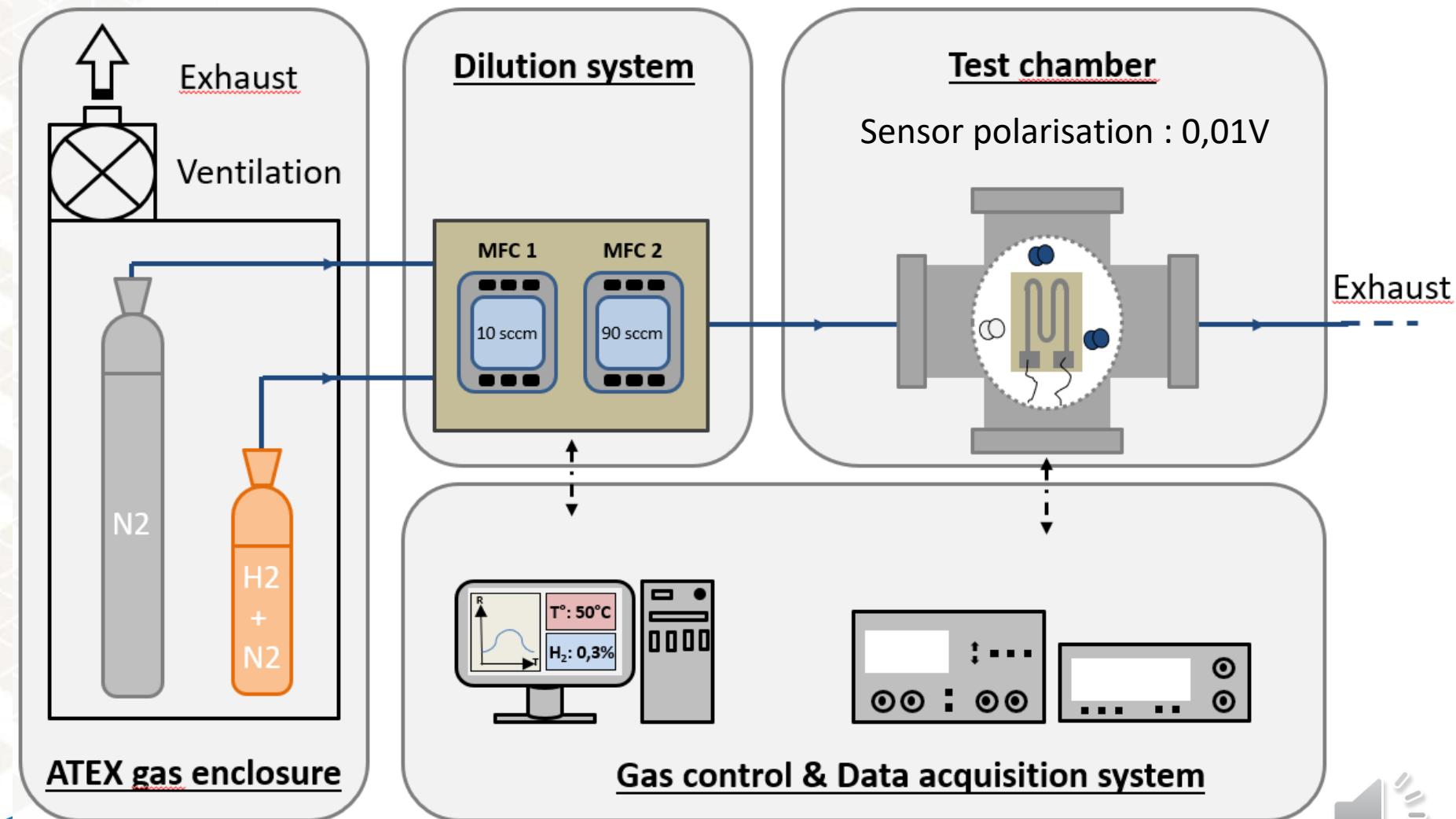


- Film crystallizes mainly with a (111) preferred orientation
- Small diffraction peak for (311) and (222) planes
- Heat treatment increases the crystallinity 13700 → 19400 counts
- Scherrer formula give a stable grain size of 20 +/- 1 nm

III. Sensor electrical characterization



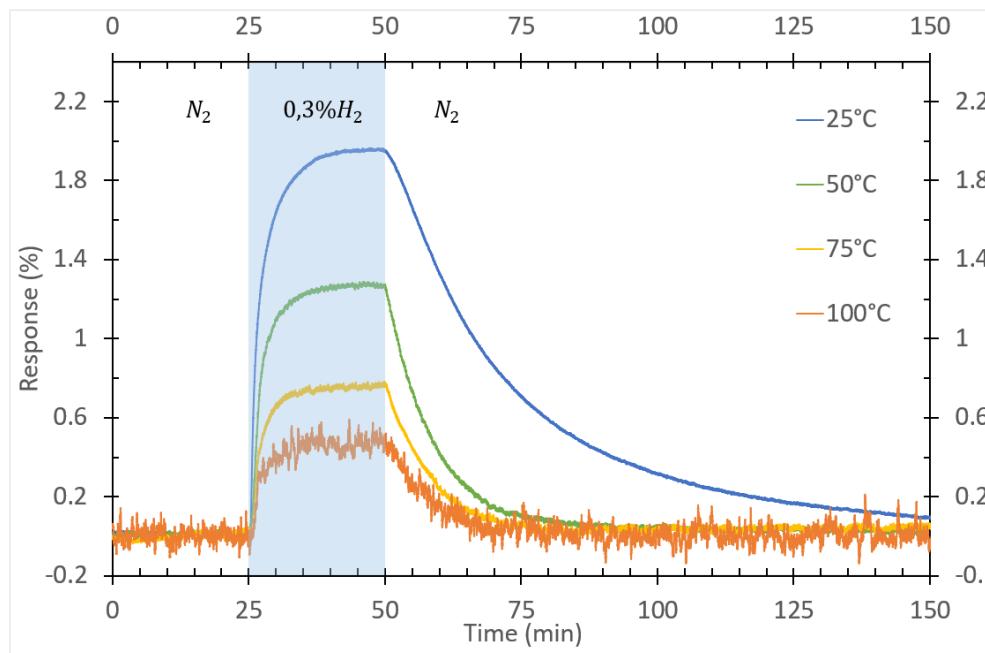
Flow rate : 100 sccm ; H₂ : 0 – 3% ; Exposure time : 25min; Operating temperature : 25°C – 100°C



Operating temperature affects sensor performances → Determine the best condition

Sensor tested at four temperatures : 25, 50, 75 & 100°C under 0.3%H₂ in N₂

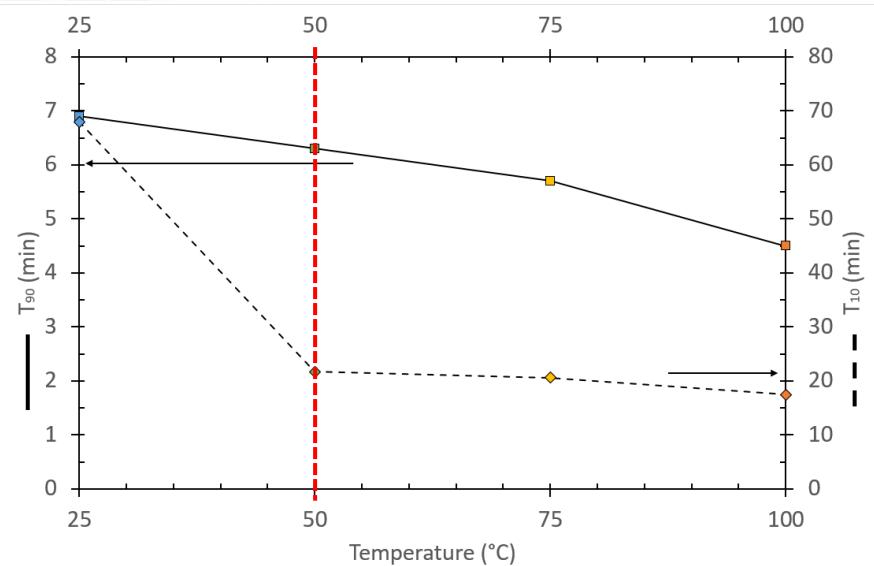
Sensor response for 0.3% H₂ at various temperatures



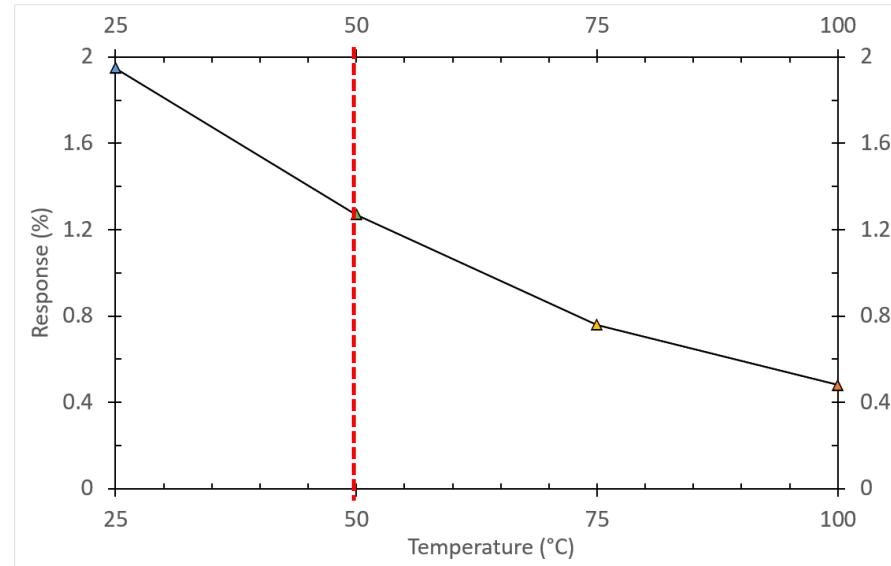
- Detection is effective at all temperatures
- Response diminishes with increasing temperature
- Response and recovery time diminish with increasing temperature
- Signal tends to be noisy at elevated temperature



T_{90} and T_{10} at various temperatures



R_s at various temperatures



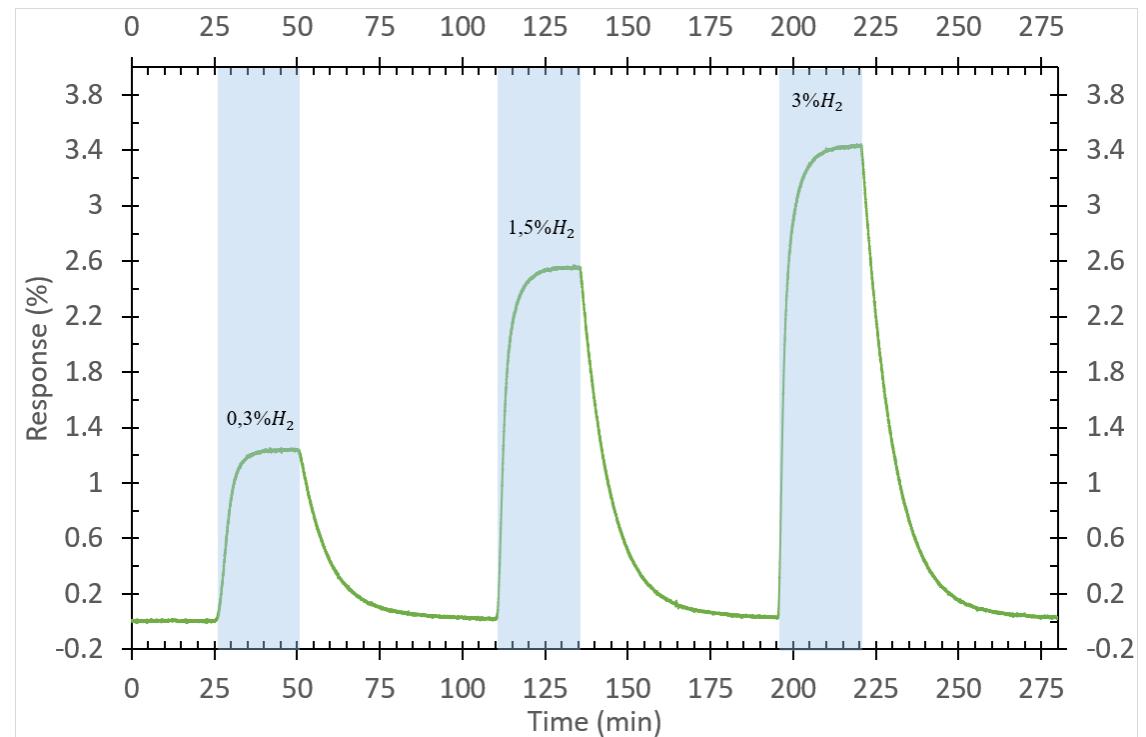
Best compromise at 50°C :

- Good response and recovery time (6 min 20s & 21 min 40s)
- Good sensitivity (1.3% for 0.3% H₂)
- Clear signal

Sensor tested for 3 H₂ concentrations at 50°C

Sensor response at 50°C for various H₂ concentration exposure

- All 3 concentrations detected
 - 1.3% for 0.3%H₂
 - 2.6% for 1.5%H₂
 - 3.4% for 3%H₂
- Stabilization of response
- Baseline recover without H₂



Sensor was able to detect various concentrations of hydrogen in N₂ with a stable baseline

IV. Conclusion



Hydrogen micro-sensor fabricated :

- Radio frequency, magnetron sputtering
- Based on a $Pd_{0.8}Au_{0.2}$ thin film
- Thermal annealing at 200°C
- Preferential growth along the (111) plane

Hydrogen sensor performance :

- Best operating condition at 50°C
- Detection from 0,3 to 3%H₂ in anaerobic environment

→ Long response and recovery time are due to filling time of the test chamber

Next step of the study :

- Characterisation of the sensitivity and selectivity in natural gas
- Use of a smaller test chamber
- Testing the effect of different Au contents in the alloy

The authors

IM2NP, MCI and RDI Teams



Ph.D Student
OCCELLI Clément



Dr. FIORIDO Tomas



Pr SEGUIN Jean-Luc



Dr. PERRIN-PELLIGRINO Carine

Contact authors:

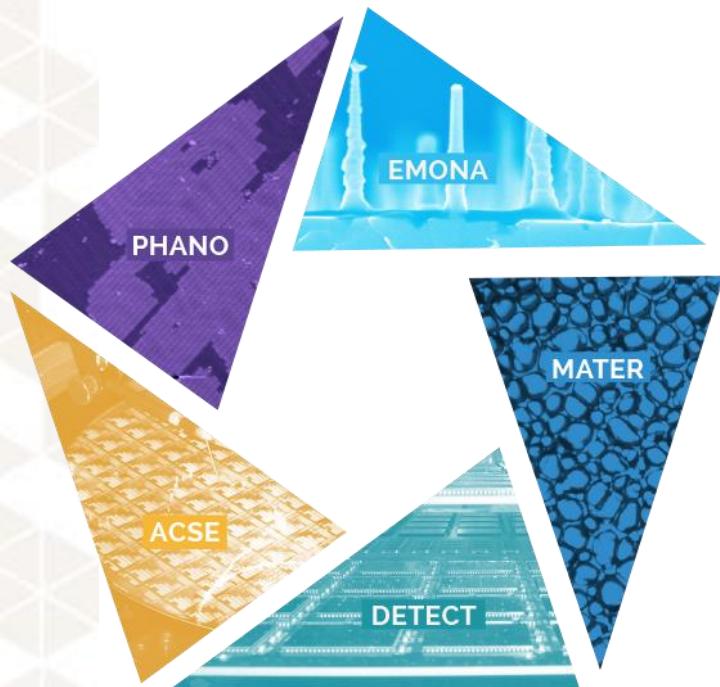
clement.occelli@im2np.fr tomas.fiorido@im2np.fr jean-luc.seguin@im2np.fr

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Institut Matériaux Microélectronique Nanosciences Provence

Thank you for your attention



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